## AMENDMENTS TO THE SPECIFICATION

Please amend the paragraph beginning on page 10, line 24, with the following new paragraph:

The display device of this embodiment is an active matrix type using an active element such as a thin film transistor for selection of pixels of the matrix display unit 8. A liquid crystal display panel (TFT-LCD) using thin-film transistors (TFT) as the active elements will be referred to as an example in the following description. And, the TFT-LCD displays in a reflective display mode, and the driving circuit 4 is integrated on the substrate 10 to have a combined structure of an LSI (Large Scale Integrated Circuit) and a polysilicon (poly-Si) thin-film transistor to realize a high-resolution display. The solar cell is produced by a low-temperature process using an organic thin-film material after forming the polysilicon TFT. The thin-film solar cell is formed by this process on the same substrate as the display device without affecting on the properties of the polysilicon TFT to realize a thin and lightweight type. A switch 9 for generating a signal to switch a display content is also disposed on the substrate 10 to instruct the control circuit 7 to switch the screen.